TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LCX373F,TC74LCX373FT,TC74LCX373FK

Low-Voltage Octal D-Type Latch with 5-V Tolerant Inputs and Outputs

The TC74LCX373 is a high-performance CMOS octal D-type latch. Designed for use in 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

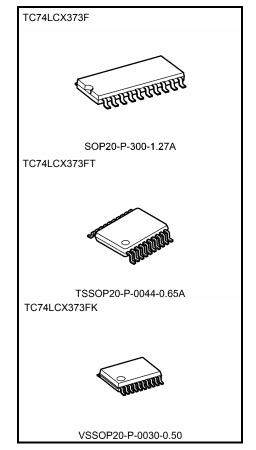
The device is designed for low-voltage (3.3 V) $V_{\rm CC}$ applications, but it could be used to interface to 5-V supply environment for both inputs and outputs.

This 8 bit D-type latch is controlled by a latch enable input (LE) and an output enable input (\overline{OE}). When the \overline{OE} input is high, the eight outputs are in a high-impedance state.

All inputs are equipped with protection circuits against static discharge.

Features

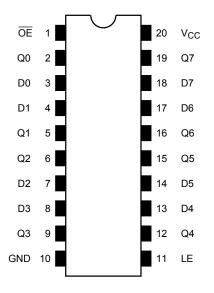
- Low-voltage operation: VCC = 2.0 to 3.6 V
- High-speed operation: $t_{pd} = 8.0 \text{ ns (max) (V}_{CC} = 3.0 \text{ to } 3.6 \text{ V)}$
- Output current: $|I_{OH}|/I_{OL} = 24 \text{ mA (min) (V}_{CC} = 3.0 \text{ V)}$
- Latch-up performance: -500 mA
- Available in JEITA SOP, TSSOP and VSSOP (US)
- · Power-down protection provided on all inputs and outputs
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 373 type



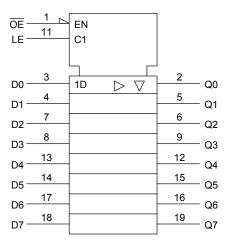
Weight

SOP20-P-300-1.27A : 0.22 g (typ.) TSSOP20-P-0044-0.65A : 0.08 g (typ.) VSSOP20-P-0030-0.50 : 0.03 g (typ.)

Pin Assignment (top view)



IEC Logic Symbol



Truth Table

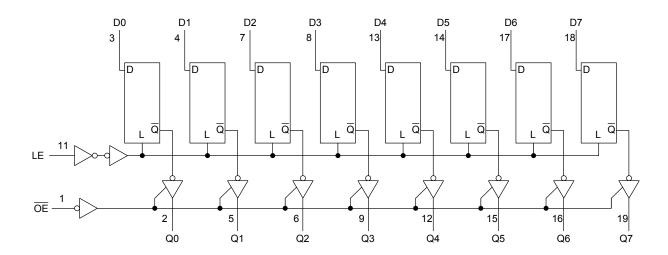
	Outputs				
ŌĒ	LE	D	Outputs		
Н	Х	Х	Z		
L	L	Х	Qn		
L	Н	L	L		
L	Н	Н	Н		

X: Don't care

Z: High impedance

Qn: Q outputs are latched at the time when the LE input is taken to a low logic level.

System Diagram





Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Power supply voltage	V _{CC}	−0.5 to 7.0	V
DC input voltage	V _{IN}	−0.5 to 7.0	٧
		-0.5 to 7.0 (Note 2)	
DC output voltage	V _{OUT}	-0.5 to $V_{CC} + 0.5$	V
		(Note 3)	
Input diode current	I _{IK}	-50	mA
Output diode current	lok	±50 (Note 4)	mA
DC output current	I _{OUT}	±50	mA
Power dissipation	P_{D}	180	mW
DC V _{CC} /ground current	I _{CC} /I _{GND}	±100	mA
Storage temperature	T _{stg}	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: Output in OFF state

Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4: Vout < GND, Vout > Vcc

Operating Ranges (Note 1)

Characteristics	Symbol	Rating	Unit	
Power supply voltage	V _{CC}	2.0 to 3.6	V	
l ower supply voltage	VCC	1.5 to 3.6 (Note 2)	V	
Input voltage	V _{IN}	0 to 5.5	V	
Output voltage	V _{OUT}	0 to 5.5 (Note 3)	٧	
Output voltage		0 to V _{CC} (Note 4)		
Output current	la/la.	±24 (Note 5)	mA	
Output current	I _{OH} /I _{OL}	±12 (Note 6)	IIIA	
Operating temperature	T _{opr}	-40 to 85	°C	
Input rise and fall time	dt/dv	0 to 10 (Note 7)	ns/V	

Note 1: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.

Note 2: Data retention only

Note 3: Output in OFF state

Note 4: High or low state

Note 5: $V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$

Note 6: $V_{CC} = 2.7 \text{ to } 3.0 \text{ V}$

Note 7: $V_{IN} = 0.8$ to 2.0 V, $V_{CC} = 3.0$ V



Electrical Characteristics

DC Characteristics (Ta = -40 to 85°C)

Characte	ristics	Symbol	Test Condition		\/ (\/)	Min	Max	Unit
	H-level	VIH			V _{CC} (V)	2.0		
Input voltage								V
	L-level	V_{IL}		<u> </u>	2.7 to 3.6	_	0.8	
			$I_{OH} = -100 \mu A$	2.7 to 3.6	V _C C - 0.2	_		
	H-level	V _{OH}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -12 \text{ mA}$	2.7	2.2	_	
				$I_{OH} = -18 \text{ mA}$	3.0	2.4	_	
Output voltage				$I_{OH} = -24 \text{ mA}$	3.0	2.2	_	V
		VOL VIN = VIH or VIL	$V_{OL} V_{IN} = V_{IH} \text{ or } V_{IL} \\ \\ \frac{I_{OL} = 100 \mu\text{A}}{I_{OL} = 12 \text{ mA}} \\ \\ I_{OL} = 16 \text{ mA} \\ \\ I_{OL} = 24 \text{ mA} \\ \\ $	$I_{OL} = 100 \ \mu A$	2.7 to 3.6		0.2	
	L-level			I _{OL} = 12 mA	2.7	_	0.4	
	L-level			AOF AIN = AIH OLAIF	I _{OL} = 16 mA	3.0		0.4
				3.0	_	0.55		
Input leakage curre	nt	I _{IN}	V _{IN} = 0 to 5.5 V	V _{IN} = 0 to 5.5 V		_	±5.0	μА
3-state output OFF state current		1.	$V_{IN} = V_{IH}$ or V_{IL}		0.74-0.0	_	±5.0	μА
		loz	V _{OUT} = 0 to 5.5 V		2.7 to 3.6			
Power-off leakage of	current	l _{OFF}	V _{IN} /V _{OUT} = 5.5 V		0		10.0	μΑ
0: 1 1			V _{IN} = V _{CC} or GND		2.7 to 3.6		10.0	
Quiescent supply co	urreni	Icc	V _{IN} /V _{OUT} = 3.6 to 5.5 V		2.7 to 3.6		±10.0	μΑ
Increase in Icc per i	nput	Δlcc	V _{IH} = V _{CC} - 0.6 V		2.7 to 3.6	_	500	

AC Characteristics (Ta = -40 to 85°C)

Characteristics	Characteristics Symbol Test Condition			Min	Max	Unit
Characteristics	Symbol	Test Condition		IVIIII	IVIAX	Offic
Propagation delay time	t _{pLH}	Figure 1, Figure 2	2.7	_	9.0	ne
(D-Q)	t _{pHL}	rigule 1, rigule 2	3.3 ± 0.3	1.5	8.0	ns
Propagation delay time	t _{pLH}	Figure 1, Figure 2	2.7	_	9.5	ns
(LE-Q)	t _{pHL}	rigule 1, rigule 2	3.3 ± 0.3	1.5	8.5	10
Output enable time	t _{pZL}	Figure 1, Figure 3	2.7	_	9.5	ns
Output enable time	t _{pZH}	rigule 1, rigule 3	3.3 ± 0.3	1.5	8.5	110
Output disable time	t _{pLZ}	Figure 1, Figure 3	2.7	_	8.5	- ns
Output disable time	t _{pHZ}		3.3 ± 0.3	1.5	7.5	
Minimum pulse width	t _w (H)	Figure 1, Figure 2	2.7	4.0		ns
(LE)	tw (11)	rigule 1, rigule 2	3.3 ± 0.3	3.3	_	115
Minimum setup time t _s	t-	Figure 1, Figure 2	2.7	2.5		ns
	ıs		3.3 ± 0.3	2.5		115
Minimum hold time	+.	Figure 1 Figure 2	2.7	1.5		ns
minimum noid tille	t _h Figure 1, Figure 2	3.3 ± 0.3	1.5	_	115	
Output to output skew	t _{osLH}	(Note)	2.7	_	_	ns
Output to output skew	t _{osHL}		3.3 ± 0.3	_	1.0	115

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Note: Parameter guaranteed by design.

 $(t_{OSLH} = |t_{PLHm} - t_{PLHn}|, \, t_{OSHL} = |t_{PHLm} - t_{PHLn}|)$



Dynamic Switching Characteristics (Ta = 25°C, input: t_r = t_f = 2.5 ns, C_L = 50 pF, R_L = 500 Ω)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Quiet output maximum dynamic V _{OL}	VOLP	$V_{IH}=3.3\;V,\;V_{IL}=0\;V$	3.3	8.0	V
Quiet output minimum dynamic V _{OL}	V _{OLV}	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	0.8	V

Capacitive Characteristics (Ta = 25°C)

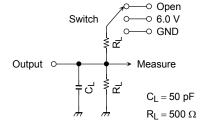
Characteristics	Symbol	Test Condition		V _{CC} (V)	Тур.	Unit
Input capacitance	C _{IN}	_		3.3	7	pF
Output capacitance	Cout	_		3.3	8	pF
Power dissipation capacitance	C _{PD}	$f_{IN} = 10 \text{ MHz}$	(Note)	3.3	25	pF

Note: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

Average operating current can be obtained by the equation:

 $ICC (opr) = CPD \cdot VCC \cdot fIN + ICC/8 (per bit)$

AC Test Circuit



Parameter	Switch
t _{pLH} , t _{pHL}	Open
t_{pLZ} , t_{pZL}	6.0 V
t _{pHZ} , t _{pZH}	GND
t_W , t_S , t_h ,	Open

Figure 1

AC Waveform

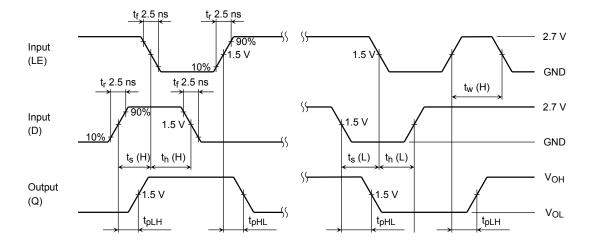


Figure 2 t_{pLH} , t_{pHL} , t_w , t_s , t_h

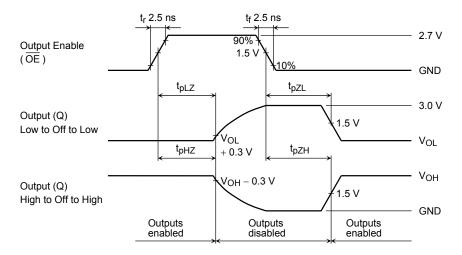
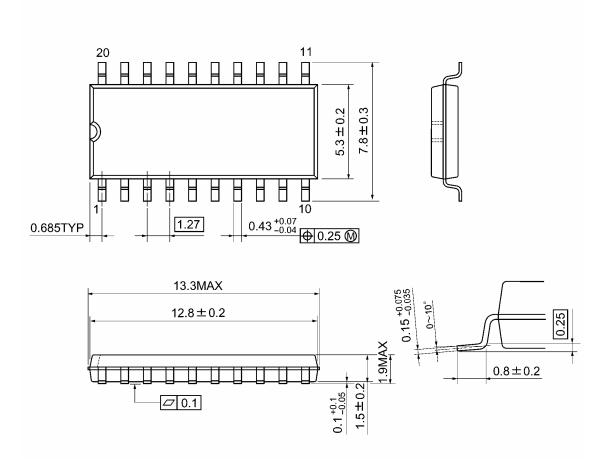


Figure 3 $\;t_{\text{pLZ}},\,t_{\text{pHZ}},\,t_{\text{pZL}},\,t_{\text{pZH}}$

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Package Dimensions

SOP20-P-300-1.27A Unit: mm



Weight: 0.22 g (typ.)

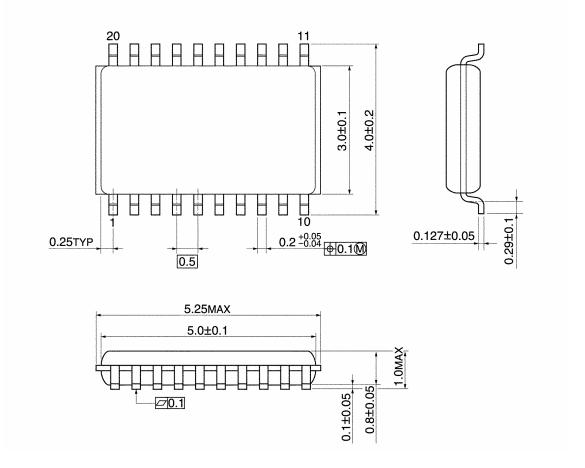
Package Dimensions

TSSOP20-P-0044-0.65A Unit: mm 6.4 ± 0.2 $0.22^{+0.09}_{-0.06}$ 0.325TYP 0.65 ♦0.13**M** 6.9MAX 6.5±0.1 1.2MAX 0.15 +0.03 0~10° 1.0±0.05 0.1 ± 0.05 S Ø.1S (0.5)0.45~0.75

Weight: 0.08 g (typ.)

Package Dimensions

VSSOP20-P-0030-0.50 Unit: mm



Weight: 0.03 g (typ.)

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20070701-EN GENERAL

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